
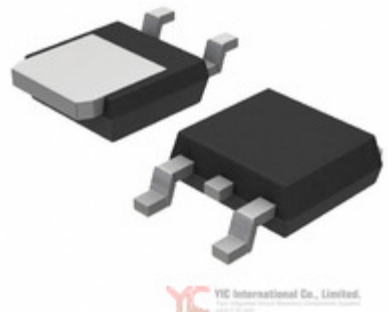
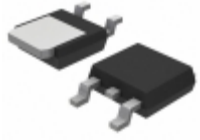
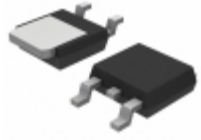
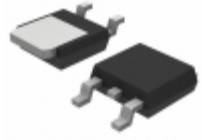

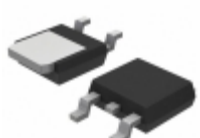
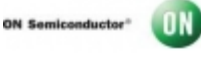
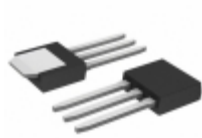

	<p>NTD3055L104T4G</p>
	<p>Hersteller-Teilenummer: NTD3055L104T4G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 12A DPAK</p> <p>Datenblätter:  NTD3055L104T4G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 134561 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD3055L104T4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 12A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	134561 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.5W (Ta), 48W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	12A (Ta)
Rds On (Max) @ Id, Vgs	104 mOhm @ 6A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	440pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V
Vgs (Max)	±15V
Verpackung	Tape & Reel (TR)



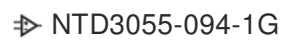
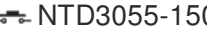
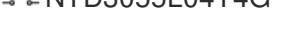


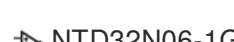

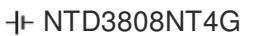

NTD3055L104T4G ist neu im Original, Suche NTD3055L104T4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD3055L104T4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD3055L104T4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD3055L170G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 9A DPAK</p>	 <p>NTD3055L104G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 12A DPAK</p>	 <p>NTD3055L170 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 9A DPAK</p>	 <p>NTD3055L04T4G ON NTD3055L04T4G ON</p>
 <p>NTD3055L104 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 12A DPAK</p>	 <p>NTD3055L104T4 AMI Semiconductor / ON Semiconductor NTD3055L104T4 ON</p>	 <p>NTD3055L170-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 9A IPAK</p>	 <p>NTD3055L170T4 ON NTD3055L170T4 ON</p>

heiße Teile

Mehr

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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